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# UTILITY PATENT APPLICATION TRANSMITTAL

(Only for new nonprovisional applications under 37 CFR 1.53(b))

Attorney Docket No.	14237-752	Total Pages	37
First Inventor or Application Identifier	Thomas A. Baginski		
Title	Electro-Explosive Device With Laminate Bridge		
Express Mail Label No.	EL68248026US		

## APPLICATION ELEMENTS

See MPEP chapter 600 concerning utility patent application contents.

ADDRESS TO:

Commissioner for Patents  
Box Patent Application  
Washington, DC 20231

- ☒ Fee Transmittal Form (e.g., PTO/SB/17)  
(Submit an original, and a duplicate for fee processing)
- ☒ Specification [Total Pages 23]  
(preferred arrangement set forth below)
  - Descriptive title of the Invention
  - Cross References to Related Applications
  - Statement Regarding Fed-Sponsored R&D
  - Reference to Microfiche Appendix
  - Background of the Invention
  - Brief Summary of the Invention
  - Brief Detailed Description of the Drawings
  - Detailed Description
  - Claim(s)
  - Abstract of the Disclosure
- ☒ Drawing(s) (37CFR 1.152) [Total Sheets 4]
- ☒ Oath or Declaration [Total Pages 6]
  - ☒ Newly executed (original or copy)
  - ☐ Copy from a prior application (37 CFR 1.63(d))  
(for continuation/divisional with Box 17 completed)
    - ☐ **DELETION OF INVENTOR(S)**  
Signed statement attached deleting inventor(s) named in the prior application, see 37 CFR 1.63(d)(2) and 1.33(b).

- ☐ Microfiche Computer Program (Appendix)
- ☐ Nucleotide and/or Amino Acid Sequence Submission  
(if applicable, all necessary)
  - ☐ Computer Readable Copy
  - ☐ Paper Copy (identical to computer copy)
  - ☐ Statement verifying identity of above copies

## ACCOMPANYING APPLICATION PARTS

- ☒ Assignment Papers (cover sheet & document(s))
- ☐ 37 CFR 3.73(b) Statement ☐ Power of Attorney  
(when there is an assignee)
- ☐ English Translation Document (if applicable)
- ☐ Information Disclosure Statement (IDS) PTO-1449 ☐ Copies of IDS Citations
- ☐ Preliminary Amendment
- ☒ Return Receipt Postcard (MPEP 503)  
(Should be specifically itemized)
- ☐ Small Entity ☐ Statement filed in prior application,  
Statement(s) Status still proper and desired
- ☐ Certified Copy of Priority Document(s)  
(if foreign priority is claimed)
- ☐ Other: .....

16. If a **CONTINUING APPLICATION**, check appropriate box and supply the requisite information below and in a preliminary amendment:

☐ Continuation ☐ Divisional ☐ Continuation-in-part (CIP) of prior application No. \_\_\_\_/\_\_\_\_

Prior application information: Examiner \_\_\_\_\_ Group/Art Unit: \_\_\_\_\_

**For CONTINUATION or DIVISIONAL APPS only:** The entire disclosure of the prior application, from which an oath or declaration is supplied under Box 4b, is considered a part of the disclosure of the accompanying continuation or divisional application and is hereby incorporated by reference. The incorporation can only be relied upon when a portion has been inadvertently omitted from the submitted application parts.

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# FEE TRANSMITTAL for FY 2000

Patent fees are subject to annual revision.

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See 37 C.F.R. §§ 1.27 and 1.28.

## Complete if Known

Application Number	Not Yet Assigned
Filing Date	September 7, 2000
First Named Inventor	Thomas A. Baginski
Examiner Name	Not Yet Assigned
Group/Art Unit	Not Yet Assigned
Attorney Docket Number	14237-752

TOTAL AMOUNT OF PAYMENT (\$1082.00)

## METHOD OF PAYMENT (check one)

1. ☒ The Commissioner is hereby authorized to charge indicated fees and credit any over payments to:

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23-2415 (Docket No. 14237-752)

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- ☐ Charge Any Additional Fee Required  
Under 37 CFR §§ 1.16 and 1.17

2. ☐ Payment Enclosed:

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## FEE CALCULATION

### 1. BASIC FILING FEE

Large Fee Code	Entity Fee (\$)	Small Fee Code	Entity Fee (\$)	Fee Description	Fee Paid
101	690	201	345	Utility filing fee	690.00
106	310	206	155	Design filing fee	
107	480	207	240	Plant filing fee	
108	690	208	345	Reissue filing fee	
114	150	214	75	Provisional filing fee	
SUBTOTAL (1)					(\$ 690.00)

### 2. EXTRA CLAIM FEES

Total Claims	Extra Claims	Fee from below	Fee Paid
28	-26** = 8	18.00	144.00
Independent Claims	4	-3** = 1	78.00
Multiple Dependent			

\*\*or number previously paid, if greater; For Reissues, see below

Large Fee Code	Entity Fee (\$)	Small Fee Code	Entity Fee (\$)	Fee Description
103	18	203	9	Claims in excess of 20
102	78	202	39	Independent claims in excess of 3
104	260	204	130	Multiple dependent claim, if not paid
109	78	209	39	**Reissue independent claims over original patent
110	18	210	9	**Reissue claims in excess of 20 and over original patent

SUBTOTAL (2) (\$ 222.00)

## FEE CALCULATION (continued)

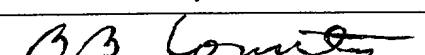
### 3. ADDITIONAL FEES

Large Fee Code	Entity Fee (\$)	Small Fee Code	Entity Fee (\$)	Fee Description	Fee Paid
105	130	205	65	Surcharge - late filing fee or oath	130.00
127	50	227	25	Surcharge - late provisional filing fee or cover sheet	
139	130	139	130	Non-English specification	
147	2,520	147	2,520	For filing a request for reexamination	
112	920	112	920	Requesting publication of SIR prior to Examiner action	
113	1,840	113	1,840	Requesting publication of SIR after Examiner action	
115	110	215	55	Extension for replay within first month	
116	380	216	190	Extension for reply within second month	
117	870	217	435	Extension for reply within third month	
118	1,360	218	680	Extension for reply within fourth month	
128	1,850	228	925	Extension for reply within fifth month	
119	300	219	150	Notice of Appeal	
120	300	220	150	Filing a brief in support of an appeal	
121	260	221	130	Request for oral hearing	
138	1,510	138	1,510	Petition to institute a public use proceeding	
140	110	240	55	Petition to revive - unavoidable	
141	1,210	241	605	Petition to revive - unintentional	
142	1,210	242	605	Utility issue fee (or reissue)	
143	430	243	215	Design issue fee	
144	580	244	290	Plant issue fee	
122	130	122	130	Petitions to the Commissioner	
123	50	123	50	Petitions related to provisional applications	
126	240	126	240	Submission of Information Disclosure Stmt	
581	40	581	40	Recording each patent assignment per property (times number of properties)	40.00
146	690	246	345	Filing a submission after final rejection (37 CFR 1.129(a))	
149	690	249	345	For each additional invention to be examined (37 CFR 1.129(b))	
Other fee (specify)		25		Request for Corrected Filing Receipt	
Other fee (specify)		55/110		Terminal Disclaimer	

\* Reduced by Basic Filing Fee Paid

SUBTOTAL (3) (\$ 170.00)

## SUBMITTED BY

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**ELECTRO-EXPLOSIVE DEVICE WITH LAMINATE BRIDGE**

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# **ELECTRO-EXPLOSIVE DEVICE WITH LAMINATE BRIDGE**

## **RELATED APPLICATION**

This patent application claims priority from United States Provisional patent application no. 60/206,864, entitled Radio Frequency and Electrostatic Discharge Insensitive Electro-Explosive Device with Reactive Semiconductor Bridge, filed May 24, 2000.

## **FIELD OF INVENTION**

This invention generally relates to an electro-explosive device. More particularly, the invention relates to a device having a laminate bridge that initiates a reaction of relatively high output energy for relatively low input energy.

## **BACKGROUND OF THE INVENTION**

In general, an electro-explosive device (EED) receives electrical energy and initiates a mechanical shock wave and/or an exothermic reaction, such as combustion, deflagration, or detonation. EEDs have been used in both commercial and government applications for a variety of purposes, such as to initiate the inflation of airbags in automobiles or to activate an energy source in an ordnance system.

Prior art EEDs include those that use a bridgewire to ignite an ordnance material. A bridgewire is a thin resistive wire attached between two contacts. The ordnance material surrounds

the bridgewire. When current is passed through the bridgewire ohmic heating results. When the bridgewire reaches the ignition temperature of the ordnance material, the ordnance material initiates. Typically, the ordnance material is a primary or pyrotechnic charge which ignites a secondary charge, which in turn ignites a main charge. EEDs that use a bridgewire have significant disadvantages in modern applications. For example, EEDs are subjected to increasing levels of electromagnetic interference (EMI) in many military and civilian applications. High levels of EMI present a serious danger because the EMI may couple electromagnetic energy through a direct or indirect path to an EED, causing it to fire unintentionally. EEDs may also be unintentionally fired by electrostatic discharge (ESD). Conventional devices to protect against unintentional discharge, such as passive filter circuits and EMI shielding, present their own space and weight problems in typical applications.

In order to reduce the sensitivity of an EED to stray signals, the total energy of the firing signal which is necessary to ignite the EED may be increased. As a result, low level stray signals may be conducted through the bridgewire without causing any ignition and only the higher level firing signal would have sufficient energy to ignite the EED. A higher magnitude firing signal, however, is not always desirable. In many applications, such as in automobile airbags, available power is severely limited, making it necessary to provide an EED that has a low firing energy, which may be near the energy level of potential spurious signals such as those from ESD or EMI sources.

One type of EED that alleviates some problems with accidental firing is called a semiconductor bridge, or SCB. An SCB may use less energy than that used by a bridgewire EED for the same no-fire level. For example, the energy required by an SCB may be an order of magnitude less than that required by a bridgewire device with the same no-fire performance. An SCB is a

ordnance material initiating device built on a semiconductor substrate. The SCB typically ignites the ordnance material with a hot plasma. When the SCB fires, it creates a high temperature plasma (for example, greater than 4000 degrees K in some cases) with high power density that ignites the ordnance material. The SCB may generate plasma in less than several microseconds as compared to the bridgewire, which may heat to the point of initiation in hundreds of microseconds. The ordnance material ignited by the SCB is typically an adjacent ordnance material or primary explosive that is ignited in a matter of microseconds and in turn ignites an output charge. The excellent heat transfer characteristics of the semiconductor provide a high capacity heat sink for the SCB and thus a relatively high no-fire level. Generally an SCB should be driven by a low impedance voltage source or a capacitive discharge to properly support an avalanche condition that results in plasma creation.

The use of EEDs in automobile airbags and other safety critical applications presents several problems in addition to the prevention of unintentional firing. For example, the reliability of an airbag EED is critical. The airbag EED must fire reliably, and must be manufactured in a way that allows some verification of reliability. Conventional SCBs have some disadvantages that make it difficult to produce verifiably reliable SCB EEDs. For example, SCBs provide a very hot but low energy ignition source that lasts only for microseconds. In typical SCBs the amount of energy output is dependent upon, and is less than, the level of energy input. In cases in which only a very small amount of output energy can be produced, the output energy may not be sufficient to provide reliable ignition.

Reliability of conventional SCB components is also difficult to verify. One reason for this is that in conventional SCBs, the ordnance material and the SCB must be tightly coupled in order to transmit the small energy output of the SCB to the primary ordnance material. That is, at the



continuous. In a top view, however, the laminate layer appears as two large sections that substantially cover the surface area of the substrate and are joined by a bridge section. The bridge section has a small cross-sectional area relative to the direction of current flow. The laminate layer is constructed as a series of individual, alternating insulating and reactive layers. The bridge section is reacted when current is passed through contacts on top of the laminate, which initiates the remainder of the laminate. As one layer of the laminate is consumed, another layer is exposed and becomes part of the conductive circuit. The output energy produced is sufficient to ignite ordnance material across a gap.

### **BRIEF DESCRIPTION OF THE DRAWINGS**

**Figure 1** is a top view of an embodiment of a semiconductor bridge (SCB).

**Figure 2** is a cross-section view of the SCB of **Figure 1**.

**Figure 3** is a top view of an embodiment of an SCB.

**Figure 4** is a cross-section view of the SCB of **Figure 3**.

**Figure 5** is a cross-section view of an electro-explosive device (EED).

### **DETAILED DESCRIPTION**

**Figures 1 and 2** illustrate one embodiment of an SCB. SCB 101 has integrally formed shunting diodes for protection against ESD events and an enhanced bridge overcoating for increased





on the surface of the chip and functions as an electrical insulator. Two spaced-apart triangular shaped openings 118 and 119 are etched in the silicon dioxide layer using any appropriate etching technique to expose the surface of the silicon chip. A first layer or pad 121 of aluminum is then deposited over the first etched opening 118 and a second layer or pad 122 of aluminum is deposited over the second etched opening 119. The aluminum pads may be deposited on the chip using any appropriate technique such as, for example, vapor deposition. The first aluminum pad 121 forms a first Schottky barrier junction 123 with the surface of the silicon chip 116 and the second aluminum pad 122 forms a second Schottky barrier junction 124 with the surface of the silicon chip 116. Accordingly, a pair of spaced apart Schottky diodes 112 and 113 are integrally formed with the SCB 101.

The SCB 101 includes a bowtie shaped layer 126 of palladium deposited over the surface of the chip. The layer 126 of palladium is configured to define a first area 107, a second area 108, and a bridge 106 that extends between and electrically couples the larger areas 107 and 108 of the bowtie shaped area 126. The first area 107 of the bowtie covers and is electrically bonded to the first Schottky diode 112 and the second area 108 of the bowtie covers and is electrically bonded to the second Schottky diode 113.

The first contact pad 109 is deposited on the surface of the first area 107 of the bowtie shaped palladium layer and the second contact pad 111 is deposited on the surface of the second area 108 of the bowtie shaped palladium layer. The contact pads 109 and 111, in one embodiment, are composite layers of Ti/Ni/Au. The contact pads 109 and 111 are contacts to which electrical leads may be bonded to the areas 107 and 108 of the bowtie shaped palladium layer 126. The electrical leads supply firing current to the bowtie shaped palladium layer 126.

The deposition, etching, and shaping of the various layers of materials on the surface of the chip 116 is accomplished using conventional integrated circuit fabrication techniques. The choices of metals for the various layers, the shape of the layers, and the relative sizes of the various portions of the layers may be different in different embodiments according to particular requirements. For example, gold or aluminum might be substituted for the palladium of the bowtie and other combinations of appropriate metals could be substituted for the Ti/Ni/Au of the contact pads.

A composite overcoat 114 is deposited atop the bridge 106. As illustrated in **Figure 2**, the composite overcoat 114 includes a layer 125 of zirconium deposited on the bridge and a layer 129 of an oxidizer such as, for example, copper oxide or iron oxide, also known as thermite, deposited atop the zirconium layer 128. Copper oxide and iron oxide are formed of molecules with relatively weak chemical bonds and thus tend to donate their oxygen readily in a chemical reaction contributing to high temperature exothermic reactions. The composite overcoat 114 can be deposited on the bridge 106 using any of a variety of known deposition techniques. Furthermore, the composite overcoat need not necessarily be deposited in layers, but could be deposited as a single layer of a mixture of metal and oxidizer. In addition, substitutes may be made for the thermite components, the zirconium and the oxidizer. For example, other weak oxides and metal fuels may be used. Any appropriate chemically explosive overcoating might be substituted in other embodiments.

In operation, the contact pads 109 and 111 are each electrically connected to a respective pair of leads by means, for example, of wirebond, conductive epoxy, or solder. The leads are then coupled to a switchable source of firing potential. When in its dormant state prior to an intentional firing, the SCB is protected from inadvertent firing, such as by ESD events, by the shunt diodes 112 and 113 and the no-fire energy of the bridge. More specifically, electric potential induced across the

contacts by an ESD event typically is much higher than the turn-on voltage of the diodes formed on the SCB. Thus, the diodes appear to ESD induced potentials as closed circuit shunts and electric current above the shunt threshold is conducted away from the resistive bridge to prevent ohmic heating of the bridge and consequent accidental firing.

In order to fire the bridge of the SCB, a firing potential that is near or above the turn-on voltage of the diodes 112 and 113 is applied to the contacts from a source capable of delivering sufficient firing potential for an appropriate length of time. The firing potential can be provided, for example, by switching a charged capacitor in series with the SCB. The portion of the firing potential that is less than the turn-on voltage of the diodes is applied across the bridge. Current then flows through the bridge causing it to heat rapidly and to vaporize in a relatively high energy plasma reaction.

The heat generated in the palladium bridge by the firing current is directly coupled to the composite overcoat 114 of the SCB. As a consequence, the overcoat is also heated rapidly until the zirconium layer of the overcoat also begins to vaporize in a plasma. This in turn initiates a chemically explosive reaction between the zirconium of the overcoat and the oxidizer layer. The result is a chemical/plasma reaction in the vicinity of the bridge 106 that is substantially more energetic than the plasma explosion of a conductive bridge alone. The explosion generates a plasma filled fireball that projects outwardly from the surface of the SCB. Thus, the composite overcoat 114 greatly enhances the efficiency of the SCB in igniting a ordnance mix packed against its surface while the integral diode shunt protects the bridge from ESD events.

**Figures 3 and 4** illustrate another embodiment of an SCB. The SCB 90 includes a greater amount of reactive materials layered over a greater surface area of the SCB as compared to the SCB

101. The SCB 90 has significantly greater energy output upon firing than for example the SCB 101, without appreciably increased energy input. The SCB 90 requires only enough energy to start and minimally sustain a reaction between two reactive materials that explode in plasma projecting outward from the surface of the SCB 90, as further described below. The SCB 90 further includes integrally formed shunting diodes for protection against ESD events.

The sensitivity of the SCB 90 may be adjusted to operate at an input electrical power level required of an application independent of the required energy level to ignite the output ordnance material. The SCB 90 may ignite insensitive materials or materials which require a large amount of heat to ignite.

Significantly, the SCB 90 provides reliable ignition across a gap between the bridge and the ordnance material. This greatly enhances reliability because an intimate interface between the bridge and the ordnance material does not need to be guaranteed for proper operation. Verification of the interface between the bridge and ordnance material is thus not required. It is only necessary to verify, using conventional techniques, that the semiconductor wafer has been correctly processed. The presence of an output charge may be easily verified by weighing or x-ray. This also reduces production costs.

**Figure 3** is a top view of the SCB 90 showing the outlines of a series of material layers set on top of each other as they would appear on a substrate (not shown). **Figure 4** is a simplified diagram of a cross-section of the SCB 90. The SCB 90 includes alternating layers of different materials which are chemically reactive with each other. Typically, one of the materials is a metal. Typically, one of the materials is an insulator, in that it has a high resistivity and low thermal conductivity relative to the metal. In one embodiment, boron is used as the insulator and titanium is

used as the metal. In other embodiments, other materials may be used. For example, the metal used may be one or more of aluminum, magnesium, and zirconium, as well as other metals. The insulator used may be one or more of calcium, manganese, and silicon, as well as other insulators.

Alternating layers, or sublayers 502 of titanium and sublayers 504 of boron are built up on a silicon dioxide insulating layer 306. The top layer of the series of layers is a "bridge" layer 203 of titanium that is in contact with the contacts pads 202. The alternating sublayers 502 and 504, and the top bridge layer 203 make up a laminate layer. The layers 502, 504, and 203 are integrally bonded in situ during the semiconductor fabrication process that produces the substrate upon which the layers appear. The resulting structure, including a bridge and fuel, is therefore monolithic. This is in contrast to prior devices which may be fabricated by depositing the fuel as powders after the semiconductor fabrication process, and then mechanically pressing the powder fuel around a bridge.

The top bridge layer 203, as shown in **Figure 3**, is a continuous layer of a metal, in this case titanium, that includes two relatively large sections 203A and 203B joined by a bridge section 203C. In other embodiments, the top layer may be boron or some other reactive material. The bridge section 203C has a small cross-sectional area relative to the direction of current flow from the contact pads 202. The cross-sectional area and geometry of the bridge section 203C determine how much energy is required to heat the bridge. The materials used in the bridge, and their geometry and thickness, affect the starting resistance of the bridge section 203C. In various embodiments, the contact pads 202 may be electrically connected to the top bridge layer 203 only, or to the top bridge layer 203 and multiple sublayers 502 and 504. The number of layers electrically connected to the contact pads 202 affects the resistance and heating characteristics of the bridge section 203C. In the case of a single layer in contact with the contact pads 202, the resistance of the layer may be reduced

by the addition of a thin layer of a material with a lower resistivity, such as gold. The resistance of the bridge may thus be adjusted to meet specific requirements.

The insulating layer 306 is built on the silicon substrate 304 substantially covers the surface area of the substrate 304. In one embodiment the insulating layer 306 is silicon dioxide. The boron layers 504 and titanium layers 502 and 203 are each approximately 0.25 microns thick. Boron is a relatively poor conductor of heat and has relatively high sheet electrical resistivity compared to titanium. Boron and titanium may be processed with standard semiconductor techniques. The boron sublayers 504 and titanium sublayers 502 are built up under the top bridge layer 203, which includes the bridge section 203C, in a series of layers until the desired thickness is achieved. The thickness of the laminate layer is dependent upon the amount of plasma required to be produced and the desired no-fire level. The thickness of the laminate layer is practically limited only by semiconductor processing technology. A stoichiometry that yields relatively high output energy is one titanium atom per two boron atoms. To achieve this, layer thicknesses may be 250 nm for titanium and 220 nm for boron. A practical number of layers, considering such factors as total processing time, is four layers of titanium and four layers of boron. In most applications, the laminate layer (which includes boron sublayers 504 and titanium sublayers 502 and bridge layer 203) may have a thickness of between two microns and fourteen microns.

The contact pads 202 are titanium/nickel/gold (Ti/Ni/Au) in one embodiment. The contact pads 202 are formed by selectively covering part of the top bridge layer 203 with a standard Ti/Ni/Au coat to form electrical contacts that can be connected, for example, via wire bonds, solder, or conductive epoxy. Titanium has adhesion characteristics that promote bonding to other materials. Nickel provides a solderable contact, if one is desired. Gold is an excellent conductor for providing





In reactive processes in which the heat released is more than the heat absorbed by the substrate or lost in plasma release, or other mechanisms, the reactive process will continue until all available reactants are consumed. In cases in which the losses exceed the energy output, the reaction will be sustained by the addition of electrical energy via the plasma until the electrical energy is discontinued or the arc length requires more voltage than the source can supply.

Tests of SCB 90 have shown that ignition of ordnance materials occurs across a gap. This eliminates the need to assure contact between the bridge and the primary ordnance material, greatly simplifying manufacture. Additionally, not having to maintain contact between the bridge and the primary ordnance material eliminates many of the reliability problems that may result, such as breaking of wire bonds during powder pressing operations. The SCB 90 can thus be reliably assembled in quantity.

In other embodiments, the area of the SCB 90 covered by layers of reactive material may be varied according to performance requirements. The shape of the area covered may also be varied. For example, multiple layers of boron and titanium, or some other appropriate materials, may be stacked as high as practicable only in the narrow bridge area between the contacts of the SCB.

**Figure 5** is a diagram of a cross-section of an electro-explosive device (EED) 60. An SCB 50 is attached to a header 62, which is formed from a ceramic or metal alloy. The SCB 50 may be similar to the SCB 101 or the SCB 90. The SCB 50 is typically attached with a nonconductive epoxy. An electrical attachment 64, for example conductive epoxy or wire bond, is applied between pins 66 on the header 62, and cap 68 is placed on the header 62 to form an enclosure filled with ordnance material 69.



## CLAIMS

What is claimed is:

1. A semiconductor bridge (SCB) device, comprising:  
a laminate layer on top of an insulating material, wherein the laminate layer comprises a series of layers of at least two reactive materials, and wherein the laminate layer comprises,  
two relatively large sections that substantially cover the surface area of the insulating material; and  
a bridge section joining the two relatively large sections;  
at least one conductive contact pad coupled to at least one of the series of layers, wherein a predetermined current through the at least one conductive contact pad causes the bridge section to initiate a reaction in which the laminate layer is involved.
2. The SCB device of claim 1, where the at least two reactive materials comprise a reactive metal and a reactive insulator, wherein the reactive insulator has a resistivity that is high relative to a resistivity of the reactive metal, and wherein the reactive metal is in contact with the at least one conductive contact pad.
3. The SCB device of claim 2, wherein the reactive metal is titanium and wherein the reactive insulator is boron.
4. The SCB device of claim 1, wherein each layer of the series of layers is approximately 0.25 microns thick.

5. The SCB device of claim 4, wherein the series of layers has a thickness of between two microns and fourteen microns.

6. The SCB device of claim 1, further comprising an integrated diode formed by an interface of the insulating material with another material.

7. The SCB device of claim 1, wherein the at least one conductive contact pad comprises titanium/nickel/gold.

8. An electro-explosive device (EED), comprising:

- a header;
- a cap coupled to a first side of the header to form an enclosure;
- ordnance material inside the enclosure;
- at least one electrically conductive pin that passes through a second side of the enclosure opposite the first side; and

a semiconductor bridge (SCB) on a substrate, wherein the substrate is coupled to the first side of the header, the SCB comprising a series of layers of at least two reactive materials on top of the substrate, wherein the series of layers comprises,

- two relatively large sections that substantially cover the surface area of the substrate;

and

- a bridge section joining the two relatively large sections;

at least one conductive contact pad coupled to at least one layer of the series of layers and to the at least one electrically conductive pin, wherein a predetermined current through the at least one electrically conductive pin causes the bridge section to initiate a reaction in which the series of layers is involved, igniting the ordnance material.

9. The EED of claim 8, where the at least two reactive materials comprise a reactive metal and a reactive insulator, wherein the reactive insulator has a resistivity that is high relative to a resistivity of the reactive metal, and wherein the reactive metal is coupled to the at least one electrically conductive pin.

10. The EED of claim 9, wherein the reactive metal is titanium and wherein the reactive insulator is boron.

11. The EED of claim 8, wherein each layer of the series of layers is approximately 0.25 microns thick.

12. The EED of claim 11, wherein the series of layers has a thickness of between two microns and fourteen microns.

13. A semiconductor bridge (SCB), comprising:  
a layer of electrically insulating material substantially covering a surface area of a substrate;  
at least one integrated diode comprising an interface of the electrically insulating material and another material;

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a bridge layer of a reactive material on top of the layer of electrically insulating material, wherein the bridge layer comprises,

two relatively large sections that substantially cover the surface area of the substrate;

and

a bridge section joining the two relatively large sections;

a laminate layer comprising a series of layers of at least two reactive materials, wherein the laminate layer covers a surface area of the bridge section; and

at least one conductive contact pad coupled to the bridge section, wherein a predetermined current through the at least one conductive contact pad causes a reaction in which the laminate layer and the bridge layer are involved.

14. The SCB of claim 13, wherein the bridge layer comprises titanium.
15. The SCB of claim 13, wherein the bridge layer comprises palladium.
16. The SCB of claim 13, where the at least two reactive materials comprise a reactive metal and a reactive insulator, wherein the reactive insulator has a resistivity that is high relative to a resistivity of the reactive metal.
17. The SCB of claim 16, wherein the reactive metal is titanium and wherein the reactive insulator is boron.

18. The SCB of claim 13, wherein each layer of the series of layers is approximately 0.25 microns thick.

19. The SCB of claim 18, wherein the laminate layer has a thickness of between two microns and fourteen microns.

20. The SCB of claim 13, wherein the metal comprising the other material is aluminum.

21. The SCB of claim 13, wherein the at least one conductive contact pad comprises titanium/nickel/gold.

22. A method of fabricating a semiconductor bridge SCB device, comprising:  
depositing a layer of electrically insulating material over a surface area of a substrate so as to substantially cover a surface area of the substrate;

selectively etching the electrically insulating material to expose the substrate;

depositing a metal in areas exposed by the etching so as to form at least one diode;

depositing a series of layers of at least two reactive materials on top of the insulating layer, wherein the series of layers comprises,

two relatively large sections that substantially cover the surface area of the substrate;

and

a bridge section joining the two relatively large sections;

coupling at least one conductive contact pad to at least one layer of the series of layers, wherein a predetermined current through the at least one conductive contact pad causes the bridge section to initiate a reaction in which the series of layers is involved.

23. The method of claim 22, where the at least two reactive materials comprise a reactive metal and a reactive insulator, wherein the reactive insulator has a resistivity that is high relative to a resistivity of the reactive metal, and wherein the reactive metal is in contact with the at least one conductive contact pad.

24. The method of claim 23, wherein the reactive metal is titanium and wherein the reactive insulator is boron.

25. The method of claim 22, wherein each layer of the series of layers is approximately 0.25 microns thick.

26. The method of claim 25, wherein the series of layers has a thickness of between two microns and fourteen microns.

27. The method of claim 22, wherein the metal is aluminum.

28. The method of claim 22, wherein the at least one conductive contact pad comprises titanium/nickel/gold.



[illegible][illegible]



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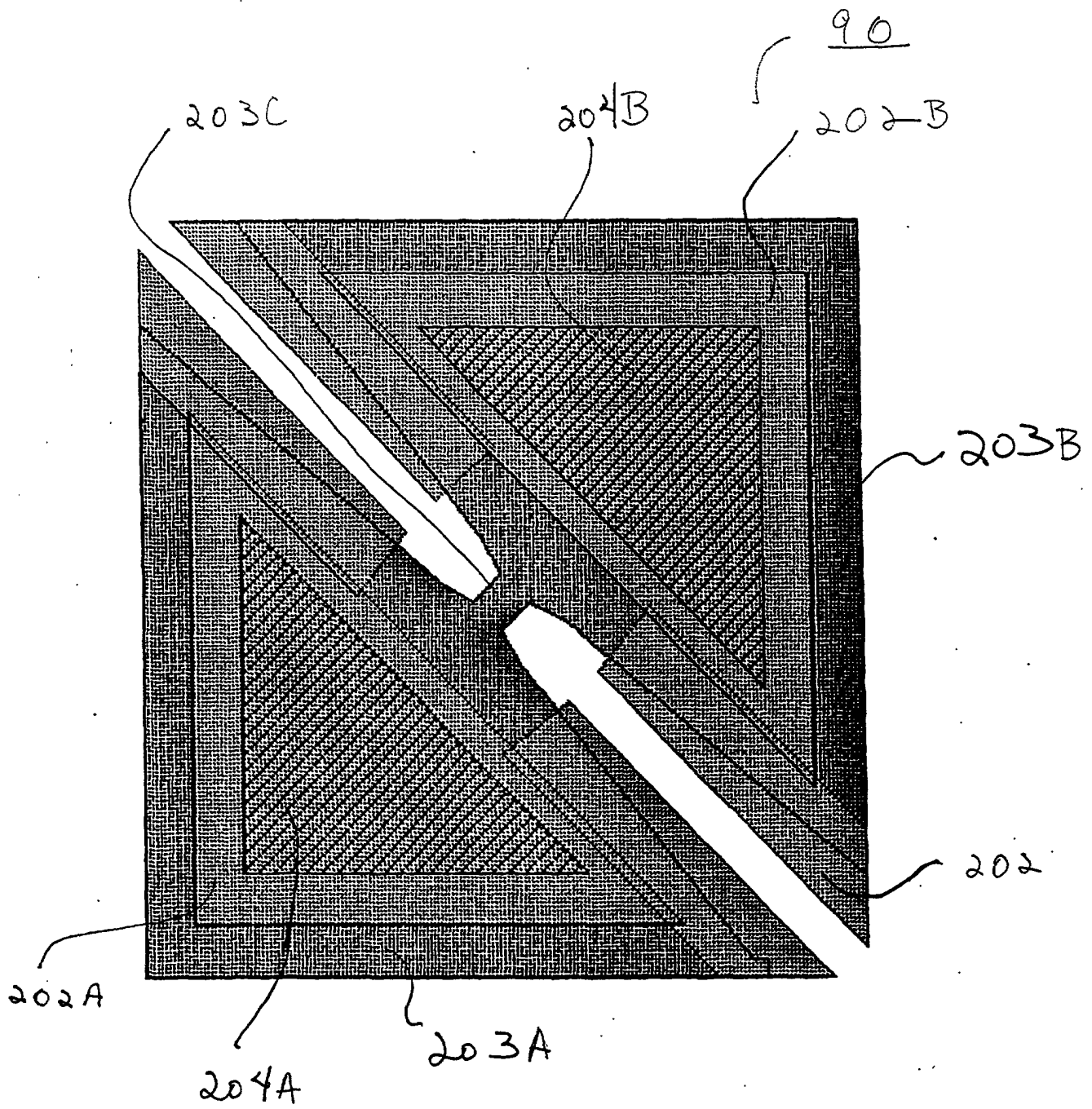


FIG. 3



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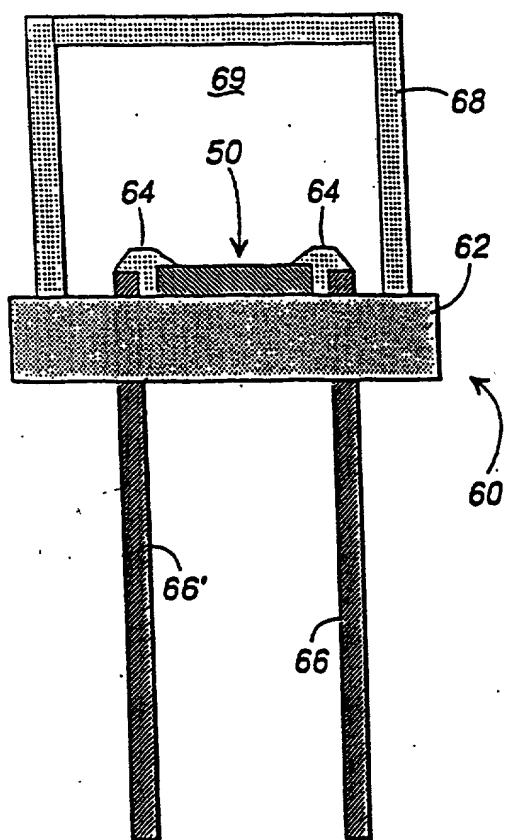


FIG. 5

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<b>DECLARATION FOR UTILITY OR DESIGN PATENT APPLICATION</b> <b>(37 CFR 1.63)</b>  <input checked="" type="checkbox"/> Declaration Submitted with Initial Filing      OR <input type="checkbox"/> Declaration Submitted after Initial Filing (surcharge (37 CFR 1.16(e)) required)	Attorney Docket Number	14237-752
	First Named Inventor	Thomas A. Baginski
	<i>COMPLETE IF KNOWN</i>	
	Application Number	Not Yet Assigned
	Filing Date	Herewith
	Group Art Unit	Not Yet Assigned
	Examiner Name	Not Yet Assigned

As a below named Inventor, I hereby declare that:

My residence, post office address, and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

**ELECTRO-EXPLOSIVE DEVICE WITH LAMINATE BRIDGE**

*(Title of the Invention)*

the specification of which

☒ is attached hereto

OR

☐ was filed on (MM/DD/YYYY)

as United States Application Number or PCT International

Application Number  and was amended on (MM/DD/YYYY)  (if applicable).

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment specifically referred to above.

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Prior Foreign Application Number(s)	Country	Foreign Filing Date (MM/DD/YYYY)	Priority Not Claimed	Certified Copy Attached?	
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
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Application Number(s)	Filing Date (MM/DD/YYYY)	<input type="checkbox"/> Additional provisional application numbers are listed on a supplemental priority data sheet PTO/SB/028 attached hereto.
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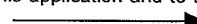
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Telephone 650-493-9300

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 U.S.C. 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Name of Sole or First Inventor:

☐ A petition has been filed for this unsigned inventor

Given Name (first and middle (if any))

Family Name or Surname

Thomas A.

Baginski

Inventor's Signature

Date

Residence: City

Auburn

State

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Country

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
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Country

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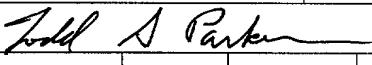
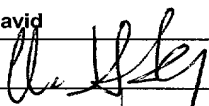
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
## DECLARATION

ADDITIONAL INVENTOR(S)  
Supplemental Sheet  
Page 1 of 1

<b>Name of Additional Joint Inventor, if any:</b>				<input type="checkbox"/> A petition has been filed for this unsigned inventor				
Given Name (first and middle (if any))				Family Name or Surname				
Todd S.				Parker				
Inventor's Signature					Date		8/22/00	
Residence: City		Hollister	State	California	Country	USA	Citizenship	USA
Post Office Address		371 Paul Drive						
Post Office Address								
City		Hollister	State	California	ZIP	95023	Country	USA
<b>Name of Additional Joint Inventor, if any:</b>				<input type="checkbox"/> A petition has been filed for this unsigned inventor				
Given Name (first and middle (if any))				Family Name or Surname				
Wm. David				Fahey				
Inventor's Signature					Date		8/26/00	
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Post Office Address		10903 Canyon Vista Drive						
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City		Cupertino	State	California	ZIP	95014	Country	USA
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Given Name (first and middle (if any))				Family Name or Surname				
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	First Named Inventor	Thomas A. Baginski
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(Title of the Invention)

the specification of which

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
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Number

☐ Additional registered practitioner(s) named on supplemental Registered Practitioner Information sheet PTO/SB/02C attached hereto.

Direct all correspondence to: ☒ Customer Number  
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OR ☐ Correspondence address below

Name Barbara B. Courtney

Address Wilson Sonsini Goodrich & Rosati

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City Palo Alto

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94304

Country U.S.

Telephone

650-493-9300

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650-493-6811

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Given Name (first and middle (if any))

Family Name or Surname

Thomas A.

Baginski

Inventor's Signature

*Thomas A. Baginski*

Date

8/21/00

Residence: City

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Post Office Address

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Auburn

State

Alabama

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36832

Country

USA

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<b>DECLARATION</b>	<b>ADDITIONAL INVENTOR(S)</b> <b>Supplemental Sheet</b> Page <u>1</u> of <u>1</u>
--------------------	---

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Inventor's Signature				Date			
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Post Office Address							
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Given Name (first and middle (if any))				Family Name or Surname			
Wm. David				Fahey			
Inventor's Signature				Date			
City	Cupertino	State	California	Country	USA	Citizenship	USA
Post Office Address		10903 Canyon Vista Drive					
Post Office Address							
City	Cupertino	State	California	ZIP	95014	Country	USA
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Inventor's Signature				Date			
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